NSN 5961-01-261-4649

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Inclosure Material:

Metal

Overall Length:

0.058 inches

Overall Diameter:

0.085 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

10.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current

Power Rating Per Characteristic:

225.0 milliwatts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0